

CMOS Digital Integrated Circuits Silicon Monolithic

## 74VHC9125FT,74VHC9126FT

#### 1. Functional Description

• 5-Bit Universal Schmitt Buffer with 3-State Outputs

#### 2. General

The 74VHC9125FT/74VHC9126FT are an ultra-high-speed 5-bit Schmitt buffer fabricated using silicon-gate CMOS technology. The 74VHC9125FT/74VHC9126FT combines low power consumption of CMOS with Schottky TTL speeds.

Y1 to Y4 outputs can be put in the high-impedance state by placing a logic HIGH on the Enable  $(\overline{G})$  input. The CONT input determines the logical inversion of data. A logic LOW on the CONT input configures the 74VHC9125FT/74VHC9126FT as an inverter; a logic HIGH on the CONT input configures the 74VHC9125FT/74VHC9126FT as a buffer.

74VHC9125FT Y5 output is an inverting type, and the 74VHC9126FT Y5 output is a non-inverting type.

All the inputs have hysteresis between the positive-going and negative-going thresholds. Thus the 74VHC9125FT/74VHC9126FT are capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

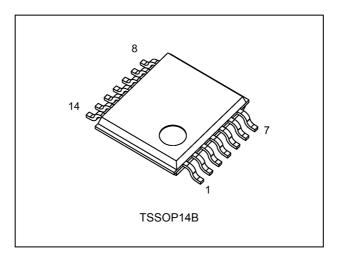
Additionally, all the inputs have a newly developed protection circuit without a diode returned to  $V_{CC}$ . This enables the inputs to be tolerant of up to 5 volts even when power supply is down. The input power-down protection capability makes the 74VHC9125FT/74VHC9126FT ideal for a wide range of applications, such as interfacing between different voltages, voltage translation from 5 V to 3 V and battery back-up circuits.

### 3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C
- (3) High speed: tpd = 5.0 ns (typ.) at  $V_{CC} = 5.0 \text{ V}$
- (4) Low supply current:  $I_{CC}$  = 2.0  $\mu A$  (max) ( $T_a$  = 25  $^{\circ}C$ )
- (5) All inputs are provided with power-down protection.
- (6) Symmetrical rise and fall delays:  $t_{PLH} \approx t_{PHL}$
- (7) Wide operating voltage range:  $V_{CC(opr)} = 2.0 \text{ V}$  to 5.5 V

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

### 4. Packaging

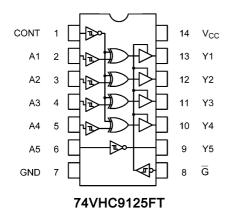


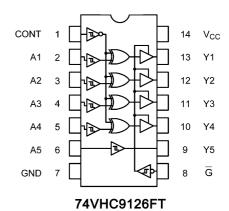
Start of commercial production

2014-06

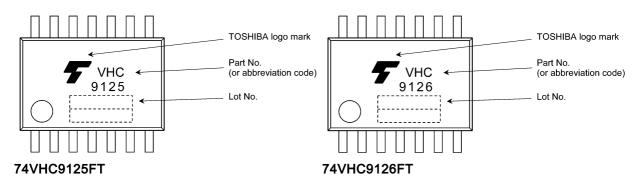


## 5. Pin Assignment





### 6. Marking



### 7. Truth Table

	Inputs	Outputs	
G	CONT	A1 to 4	Y1 to 4
Н	Х	Х	Z
L	L	L	Н
L	L	Н	٦
L	Н	L	L
L	Н	Н	Н

Inputs	Outputs					
A5	Y5(9125)	Y5(9126)				
L	Н	L				
Н	L	Н				

- X: Don't care (L or H)
- Z: High impedance



## 8. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to 7.0	V
Output voltage	V <sub>OUT</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>		-20	mA
Output diode current	I <sub>OK</sub>		±20	mA
Output current	I <sub>OUT</sub>		±25	mA
V <sub>CC</sub> /ground current	Icc		±50	mA
Power dissipation	P <sub>D</sub>	(Note 1)	180	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of  $T_a$  = -40 to 85 °C. From  $T_a$  = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

### 9. Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 125	°C

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V<sub>CC</sub> or GND.



### 10. Electrical Characteristics

## 10.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
Positive threshold voltage	$V_P$	_		3.0	_	_	2.20	V
				4.5			3.15	
				5.5			3.85	
Negative threshold voltage	V <sub>N</sub>	_		3.0	0.90			V
				4.5	1.35			
				5.5	1.65	_	_	
Hysteresis voltage	V <sub>H</sub>	_		3.0	0.30	_	1.20	V
				4.5	0.40	_	1.40	
				5.5	0.50		1.60	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	2.0	_	\
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			$I_{OH}$ = -4 mA	3.0	2.58	_	_	
			$I_{OH}$ = -8 mA	4.5	3.94	_		
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OL}$ = 50 $\mu$ A	2.0		0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	ı	0.0	0.1	
			$I_{OL}$ = 4 mA	3.0		_	0.36	
			$I_{OL}$ = 8 mA	4.5	_	_	0.36	
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	_	±0.25	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5			±0.1	μΑ
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		5.5	_		2.0	μА



## 10.2. DC Characteristics (Unless otherwise specified, $T_a$ = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
Positive threshold voltage	V <sub>P</sub>	_		3.0	_	2.20	V
				4.5	_	3.15	
				5.5	_	3.85	]
Negative threshold voltage	V <sub>N</sub>	_		3.0	0.90	_	V
				4.5	1.35	_	
				5.5	1.65	_	]
Hysteresis voltage	V <sub>H</sub>	_		3.0	0.30	1.20	V
				4.5	0.40	1.40	
				5.5	0.50	1.60	]
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	]
			I <sub>OH</sub> = -4 mA	3.0	2.48	_	
			I <sub>OH</sub> = -8 mA	4.5	3.80	_	]
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0		0.1	V
				3.0	_	0.1	]
				4.5	_	0.1	]
			I <sub>OL</sub> = 4 mA	3.0	-	0.44	]
			I <sub>OL</sub> = 8 mA	4.5		0.44	
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	±2.50	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5		±1.0	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	20.0	μА



## 10.3. DC Characteristics (Unless otherwise specified, $T_a$ = -40 to 125 °C)

Characteristics	Symbol	Test Cond	ition	V <sub>CC</sub> (V)	Min	Max	Unit
Positive threshold voltage	V <sub>P</sub>	_		3.0	_	2.20	٧
				4.5	_	3.15	
				5.5	_	3.85	
Negative threshold voltage	V <sub>N</sub>	_		3.0	0.90	_	V
				4.5	1.35	_	
				5.5	1.65	_	
Hysteresis voltage	V <sub>H</sub>	_		3.0	0.30	1.20	V
				4.5	0.40	1.40	
				5.5	0.50	1.60	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			$I_{OH} = -4 \text{ mA}$	3.0	2.40	_	
			$I_{OH} = -8 \text{ mA}$	4.5	3.70	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			$I_{OL} = 4 \text{ mA}$	3.0	_	0.55	
			$I_{OL}$ = 8 mA	4.5	_	0.55	
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	±10.0	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±2.0	μА
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	40.0	μΑ



## 10.4. AC Characteristics (Unless otherwise specified, $T_a$ = 25 °C, Input: $t_r$ = $t_f$ = 3 ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3\pm0.3$	15		6.0	8.0	ns
(A1 to A4 - Y1 to Y4)					50		9.0	12.5	
				$5.0 \pm 0.5$	15		5.0	5.5	
					50	1	7.0	8.5	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3 \pm 0.3$	15	1	8.5	11.5	ns
(CONT - Y1 to Y4)					50		13.0	17.0	
				5.0 ± 0.5	15	_	6.5	8.0	
					50	_	10.5	12.5	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3 \pm 0.3$	15	_	6.0	8.0	ns
(A5 - Y5)					50	_	9.0	12.5	
				5.0 ± 0.5	15	_	5.0	5.5	
					50	_	7.0	8.5	
3-state output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	15	_	6.0	8.0	ns
					50	_	10.5	13.5	
				5.0 ± 0.5	15	_	4.5	5.5	
					50	_	9.0	10.5	
3-state output disable time	$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	$3.3\pm0.3$	50	_	12.5	13.5	ns
				5.0 ± 0.5	50	_	9.0	9.5	
Output skew	t <sub>osLH</sub> ,	(Note 1)	_	$3.3 \pm 0.3$	50	_	_	1.5	ns
(A1 to A4 - Y1 to Y4)	t <sub>osHL</sub>			5.0 ± 0.5	50	_	_	1.0	
Input capacitance	C <sub>IN</sub>		_			_	4	10	pF
Output capacitance	C <sub>OUT</sub>		_			_	6		pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 2)	f <sub>IN</sub> = 1 MHz				10	_	pF

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m - t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m - t_{PHL}n|$ )

Note 2:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/5$  (per bit)



# 10.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3\pm0.3$	15	1.0	10.0	ns
(A1 to A4 - Y1 to Y4)					50	1.0	15.0	
				$5.0 \pm 0.5$	15	1.0	7.0	
					50	1.0	10.0	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3\pm0.3$	15	1.0	13.5	ns
(CONT - Y1 to Y4)					50	1.0	20.5	
				$5.0 \pm 0.5$	15	1.0	9.5	
					50	1.0	15.0	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	3.3 ± 0.3	15	1.0	10.0	ns
(A5 - Y5)					50	1.0	15.0	
				5.0 ± 0.5	15	1.0	7.0	
					50	1.0	10.0	
3-state output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	15	1.0	9.5	ns
					50	1.0	16.5	
				$5.0 \pm 0.5$	15	1.0	6.5	
					50	1.0	12.5	
3-state output disable time	$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	50	1.0	16.0	ns
				$5.0 \pm 0.5$	50	1.0	11.0	
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$3.3 \pm 0.3$	50		1.5	ns
(A1 to A4 - Y1 to Y4)				$5.0 \pm 0.5$	50		1.0	
Input capacitance	C <sub>IN</sub>						10	pF

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m - t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m - t_{PHL}n|$ )

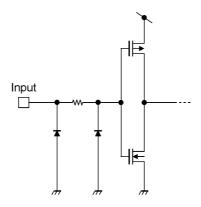


## 10.6. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3 \pm 0.3$	15	1.0	11.5	ns
(A1 to A4 - Y1 to Y4)					50	1.0	17.0	
				$5.0 \pm 0.5$	15	1.0	8.0	
					50	1.0	11.0	
Propagation delay time	$t_{PLH}, t_{PHL}$		_	$3.3 \pm 0.3$	15	1.0	15.0	ns
(CONT - Y1 to Y4)					50	1.0	23.0	
				$5.0 \pm 0.5$	15	1.0	10.5	
					50	1.0	17.0	
Propagation delay time	$t_{PLH}, t_{PHL}$		_	$3.3 \pm 0.3$	15	1.0	11.5	ns
(A5 - Y5)					50	1.0	17.0	
				$5.0 \pm 0.5$	15	1.0	8.0	
					50	1.0	11.0	
3-state output enable time	$t_{PZL}, t_{PZH}$		$R_L = 1 k\Omega$	$3.3\pm0.3$	15	1.0	10.5	ns
					50	1.0	18.5	
				$5.0 \pm 0.5$	15	1.0	7.5	
					50	1.0	14.0	
3-state output disable time	$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	50	1.0	18.0	ns
				$5.0 \pm 0.5$	50	1.0	12.0	
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$3.3 \pm 0.3$	50	_	1.5	ns
(A1 to A4 - Y1 to Y4)				$5.0 \pm 0.5$	50	_	1.0	
Input capacitance	C <sub>IN</sub>		_			_	10	pF

Note 1: Parameter guaranteed by design.  $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$ 

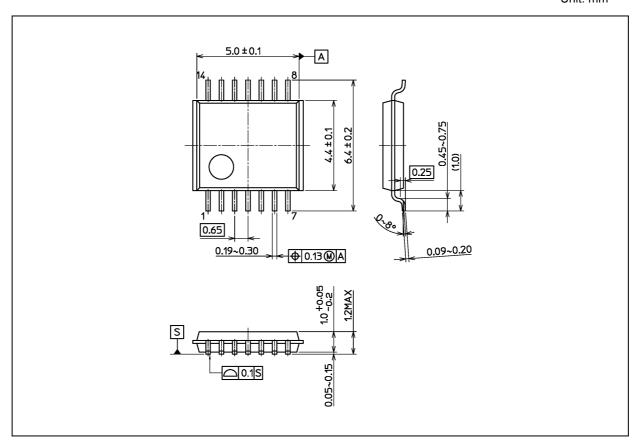
## 11. Internal Equivalent Circuit





## **Package Dimensions**

Unit: mm



Weight: 0.054 g (typ.)

Package Name(s)

Nickname: TSSOP14B



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LXV200-024SW 74AUP2G34FW3-7 HEF4043BP PI74FCT3244L MC74HCT365ADTR2G Le87401NQC Le87402MQC 028192B
042140C 051117G 070519XB NL17SZ07P5T5G NLU1GT126AMUTCG 74AUP1G17FW5-7 74LVC2G17FW4-7 CD4502BE 59628982101PA 5962-9052201PA 74LVC1G125FW4-7 NL17SH17P5T5G NL17SH125P5T5G NLV37WZ07USG RHRXH162244K1
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